Simulation of Silicon Detector Response for β-delayed Proton Emission



JINA Frontiers Lake Geneva, WI October 22, 2010

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Ep > 500 keV



Ep == 4070 ke



Purpose of Simulations



β-Delayed Proton Emission

Implantation into DSSD



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Experimental Set-Up



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Benchmarking of Simulation

- benchmarked GEANT4 with MCNPX
 - Ex: ²⁰⁷Bi *e*⁻ emitter



Comparison with B⁺-decay data

- Detector Resolution
 - Gaussian Dist.
 - $\sigma[\text{MeV}] =$
 - $0.022/\sqrt{(E)} + 0.034$
- Threshold
 - tanh function
 - Center = 280 keV
 - Width = 60 keV



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*Channel to Energy calibrations for data from DSSD supplied by M. del Santo



Comparison to \$\$\$ Data*



Impact of Summing Effect*



•Detector Resolution:

- Gaussian Distribution
- σ [MeV] = 0.022/ $\sqrt{(E)}$ +0.034

•Extract E_p from data via shift

*Preliminary Result

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Supplementary slides





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(40 keV) (5/2-)

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DSSD, correct length:height = 80/1





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